THIS REVIS	SION DESC		OF REVISION AS BEEN AUTH	• •	OCUMENT LISTED.	1. DATE (YYMMDD) 94-08-29	Form Approved OMB No. 0704-0188
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4. ORIGINAT	1507 Wilmington Pike					5. CAGE CODE 67268	6. NOR NO. 5962-R267-94
a. TYPED NA <i>Last)</i>	ME (First,	Middle Initial,	Dayton OH 4	•		7. CAGE CODE 67268	8. DOCUMENT NO. 5962-88503
9. TITLE OF MICROCIR		NT EAR, Dual MOSFET	Drivers, MONO	DLITHIC SILICON	10. REVISION LETT	ER	11. ECP NO.
					a. CURRENT E	b. NEW F	No ECP necessary
12. CONFIGU	JRATION	TEM (OR SYSTEM) TO WHICH EC	CP APPLIES			
13. DESCRIP	TION OF	REVISION					
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14. THIS SEC	CTION FO	R GOVERNMENT L	JSE ONLY				
a. (X one)	Х	(1) Existing docume	ent supplemente	d by the NOR may be	used in manufacture.		
		(2) Revised docume	ent must be rece	ived before manufactu	rer may incorporate this	change.	
		(3) Custodian of ma	aster document s	hall make above revis	ion and furnish revised	document.	
b. ACTIVITY DESC-ELDS	AUTHORI	ZED TO APPROVE	CHANGE FOR	GOVERNMENT	c. TYPED NAME <i>(Fii</i> Michael A. Frye	st, Middle Initial, Last)	
d. TITLE				e. SIGNATURE	-		f. DATE SIGNED
Chief, Micro	electronics	Branch		Michael A. Frye			<i>(YYMMDD)</i> 94-08-29
15a. ACTIVIT	Y ACCOM	IPLISHING REVISIO	DN	b. REVISION COMP	PLETED (Signature)		c. DATE SIGNED (YYMMDD)
DESC-ELD	S			Sandra Rooney			94-08-29

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1. ORIGINATOR NAM	E AND ADDRESS		2. CAGE CODE	3. NOR NO.
Defense Elec	tronics Supply	y Center	67268	5962-R154-93
Dayton, Ohio	45444-5277		4. CAGE CODE 67268	5. DOCUMENT NO.
			07200	5962-88503
6. TITLE OF DOCUM		MOSFET DRIVERS, MONOLITHIC SILICON	7. REVISION LETTER (Current) D	(New) E
			(33223337)	(1.0)
			8. ECP NO.	
9. CONFIGURATION	ITEM (OR SYST	EM) TO WHICH ECP APPLIES ALL		
10. DESCRIPTION O	F REVISION			
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11. THIS SECTION	FOR GOVERNMEN	I USE ONLY		
a. CHECK ONE [X]EXISTING DOCUMEN BY THIS NOR MAY AND		D [] REVISED DOCUMENT MUST BE RECEIVED BEFORE MANUFACTUR		MASTER DOCUMENT BOVE REVISION
MANUFACTURE.		MAY INCORPORATE THIS CHANG	E. FURNISH REVI	SED DOCUMENT TO:
b. ACTIVITY AUTHO		SIGNATURE AND TITLE	DATE (YYMMDD)	
DESC		Michael A. Frye BRANCH CHIEF	93-05-04	

REVISION COMPLETED (Signature)

Dan Wonnell

DESC

12. ACTIVITY ACCOMPLISHING REVISION

DATE (YYMMDD)

93-05-04

NOTICE OF (See MIL-STD-4 This revision described below h listed.	REVISION (NOR) 80 for instructions) as been authorized for the document	DATE (YYMMDD) 92-12-04	Form Approved OMB No. 0704-0188
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1. ORIGINATOR NAME AND ADDRESS		2. CAGE CODE	3. NOR NO.
Defense Electronics Suppl	y Center	67268	5962-R015-93
Dayton, Ohio 45444-5277		4. CAGE CODE 67268	5. DOCUMENT NO.
			5962-88503
6. TITLE OF DOCUMENT Microci	rcuit, Linear, Dual MOSFET Drivers, hic Silicon.	LETTER	
		(Current) C	(New) D
		8. ECP NO. 5962-88503ECP-0	1
9. CONFIGURATION ITEM (OR SYST	EM) TO WHICH ECP APPLIES		
10. DESCRIPTION OF REVISION			
Sheet 1: Revisions ltr colu Revisions descript Revisions date col Revision level blo	ion column; add "Changes in accorda umn; add "92-12-04".		-93".
	rent (I _{IN}) test, for condition -5 V "±1 mA" to "±10 mA". ck: add "D".		ogroup 1, change
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Revision level blo	ck: add "D".		
Sheet 8: Figure 2; Invertin drivers to inverti Revision level blo		lock diagram, change th	he non-inverting
11. THIS SECTION FOR GOVERNMEN	T USE ONLY		
a. CHECK ONE [X]EXISTING DOCUMENT SUPPLEMENTE BY THIS NOR MAY BE USED IN AND MANUFACTURE.	D [] REVISED DOCUMENT MUST BE RECEIVED BEFORE MANUFACTUR MAY INCORPORATE THIS CHANG	RER SHALL MAKE A	MASTER DOCUMENT BOVE REVISION
TO:	I INCOMORATE INTO CHANG		
b. ACTIVITY AUTHORIZED TO APPROVE CHANGE FOR GOVERNMENT DESC-ECS	M. A. Frye BRANCH	DATE (YYMMDD) 92-12-04	
	CHIEF		
12. ACTIVITY ACCOMPLISHING REVISION DESC-ECS	REVISION COMPLETED (Signature) Sandra Rooney	DATE (YYMMDD) 92-12-04	

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С	Add ve	Redrawn with changes. Table I changes. Delete ve Add vendor CAGE 1ES66 for device types 01, 02, a CAGE 60496 for device types 01 through 09.						e vend 2, and	or CA(03. A	CAGE 15818.			2-10-2	2		M. A. Frye			
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SHEET REV SHEET REV STATL OF SHEETS PMIC N/A STA MICRO DRA THIS DRAW	JS S NDAR OCIRC AWING ING IS AVA	D UIT AILABLE	REV SHE PREF Ma CHEC Ray	/ EET PARECircia B	D BY S. Kelle BY Innin	C 1	С	С	C 4	C 5 DEFI	C 6 ENSE	C 7 ELI DAY	C 8 ECTR	C 9 PONIA, OF	CS SHIO	C 11 SUPP 454	LY (ref
MICRO DRA THIS DRAW FOR U	JS S S S S S S S S S S S S S S S S S S	D UIT S AILABLE L S THE	REV SHE PREF Ma CHEC Ra APPF D. A	/ PAREC Ircia B CKED y Mon	D BY E Kelle BY Inin D BY Enzo	C 1	C 2	C 3	C 4	C 5 DEFI	C 6 CIRC	C 7 DAY	C 8 ECTR TON	C 9 PONIA, OF	CS S	C 11 SUPP 454 AL N	LY (ET	

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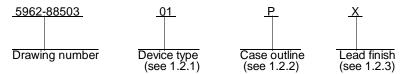
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DISTRIBUTION STATEMENT A. Approved for public release; distribution is unlimited.

С

1. SCOPE

- 1.1 <u>Scope</u>. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices".
 - 1.2 Part or Identifying Number (PIN). The complete PIN shall be as shown in the following example:



1.2.1 <u>Device type(s)</u>. The device type(s) shall identify the circuit function as follows:

Device type	Generic number	Circuit function	Output current
01 02 03 04 05 06	TSC426, MIC426 TSC427, MIC427 TSC428, MIC428 MIC4423 MIC4424 MIC4425	Dual power MOSFET driver Dual power MOSFET driver Dual power MOSFET driver Dual high power MOSFET driver Dual high power MOSFET driver Dual high power MOSFET driver	1.5 A dc 1.5 A dc 1.5 A dc 3.0 A dc 3.0 A dc 3.0 A dc
07	MIC4426	Dual power MOSFET driver with latch	
08	MIC4427	proof output for inductive loads Dual power MOSFET driver with latch	1.5 A dc
09	MIC4428	proof outputs for inductive loads Dual power MOSFET driver with latch proof outputs for inductive loads	1.5 A dc 1.5 A dc

1.2.2 Case outline(s). The case outline(s) shall be as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	<u>Terminals</u>	Package style
P	GDIP1-T8 or CDIP2-T8	8	dual-in-line
2	CQCC1-N20	20	square leadless chip carrier

1.2.3 <u>Lead finish</u>. The lead finish shall be as specified in MIL-M-38510. Finish letter "X" shall not be marked on the microcircuit or its packaging. The "X" designation is for use in specifications when lead finishes A, B, and C are considered acceptable and interchangeable without preference.

1.3 Absolute maximum ratings.

Supply voltage (V _S): Device types 01 through 03	20 V dc
Device types 04 through 09	22 V dc
Input voltage (V _{IN}): Device types 01 through 03	V _S + 0.3 V dc to GND - 0.3 V dc V _S + 0.5 V dc to GND - 5.0 V dc
Device types 04 through 09 Output current (per pin, capacitance load):	V _S + 0.5 V dc to GND - 5.0 V dc
Device types 01, 02, 03, 07, 08, and 09	1.5 A dc
Device types 04, 05, and 06	3.0 A dc
Peak supply current or GND current (per pin)	3.0 A dc
Storage temperature range	-55°C to +125°C
Maximum power dissipation (P _D): Case P	
Case P	800 mW 1/
Case 2	1.8 W 2/
Lead temperature (soldering, 10 seconds)	+300° C
Junction temperature (T ₁)	+150°C
Junction temperature (T_J) Thermal resistance, junction-to-case (Θ_{JC})	See MIL-STD-1835
,,	

 $\overline{\frac{1}{D}}$ Derate linearly at 6.4 mW/° C above T_A = +25° C. $\overline{\frac{2}{D}}$ Derate linearly at 14.4 mW/° C above T_A = +25° C.

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Supply voltage rangeAmbient operating temperature range (T_{Δ})	4.5 V dc ≤ V _S -55°C to +125°	≤ 18 V dc °C	
2. APPLICABLE DOCUMENTS	33 0 13 1 120	-	
2.1 Government specification, standards, and bulletin. Unles bulletin of the issue listed in that issue of the Department of Defensionicitation, form a part of this drawing to the extent specified herei	ss otherwise speci se Index of Specifi	fied, the following specificati cations and Standards spec	ion, standards, and cified in the
SPECIFICATION	•••		
MILITARY			
MIL-M-38510 - Microcircuits, General Speci	ification for.		
STANDARD			
MILITARY			
MIL-STD-883 - Test Methods and Procedu MIL-STD-1835 - Microcircuit Case Outlines.	res for Microelectr	onics.	
BULLETIN			
MILITARY			
MIL-BUL-103 - List of Standardized Military	Drawings (SMD's).	
(Copies of the specification, standards, and bulletin required by should be obtained from the contracting activity or as directed by t	manufacturers in c he contracting act	connection with specific acquivity.)	uisition functions
2.2 $$ $\!$ $\!$ $\!$ $\!$ $\!$ $\!$ $\!$ $\!$ $\!$ $\!$	the text of this dra	wing and the references cite	ed herein, the text of
3. REQUIREMENTS			
3.1 <u>Item requirements</u> . The individual item requirements shause of MIL-STD-883 in conjunction with compliant non-JAN devices	all be in accordanc es" and as specific	e with 1.2.1 of MIL-STD-883 ed herein.	3, "Provisions for the
3.2 <u>Design, construction, and physical dimensions</u> . The des MIL-M-38510 and herein.	sign, construction,	and physical dimensions sh	all be as specified in
3.2.1 Case outline(s). The case outline(s) shall be in accord	ance with 1.2.2 he	erein.	
3.2.2 <u>Terminal connections</u> . The terminal connections shall	be as specified or	figure 1.	
3.3 <u>Electrical performance characteristics</u> . Unless otherwise specified in table I and shall apply over the full ambient operating to	specified, the elecenter specified, the elecenter specified, the elecenter specified is specified.	ctrical performance characte	eristics are as
3.4 <u>Electrical test requirements</u> . The electrical test requirements for each subgroup are described in table I.	ents shall be the s	ubgroups specified in table I	II. The electrical
3.5 <u>Marking</u> . Marking shall be in accordance with MIL-STD-in 1.2 herein. In addition, the manufacturer's PIN may also be ma	883 (see 3.1 here rked as listed in M	in). The part shall be marke IL-BUL-103 (see 6.6 herein)	ed with the PIN listed
3.6 <u>Certificate of compliance</u> . A certificate of compliance sha approved source of supply in MIL-BUL-103 (see 6.6 herein). The an approved source of supply shall affirm that the manufacturer's and the requirements herein.	all be required fron certificate of comp product meets the	n a manufacturer in order to bliance submitted to DESC-l requirements of MIL-STD-8	be listed as an EC prior to listing as 883 (see 3.1 herein)
STANDARDIZED	SIZE A		
MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER			
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ESC FORM 193A			

1.4 Recommended operating conditions.

	TA	BLE I. Electrical per	formance cha	racteristics	<u>S</u> .			
Test	Symbol Conditions			Device type	Group A subgroups	Limits		Unit
		-55° C \leq T _A \leq +1 4.5 V \leq V _S \leq 18 unless otherwise s	25 C 3 V pecified	іуре	subgroups	Min	Max	-
Logic "1" input voltage	V _{IH}			All	1,2,3	2.4		V
Logic "0" input voltage	V _{IL}			All	1,2,3		0.8	-
Input voltage range	V _{IN} (max)			01,02, 03	1,2,3	0	V _S	-
	(a.y			04,05, 06,07 08,09	1,2,3	-5	V _S + 0.5	
Input current	I _{IN}	0 V ≤ V _{IN} ≤ V _S		01,02, 03	1		±1	μΑ
				03	2, 3		±10	_
		$0 \ V \le V_{IN} \le V_{S}$ $-5 \ V \le V_{IN} \le 0$		04,05	1		±1	_
				06,07 08,09	2, 3		±10	
				04,05	1		±1	mA
				06,07 08,09	2, 3		±10	
High output voltage	V _{OH}	R _L = ∞		All	1,2,3	V _S - 25 mV		V
Low output voltage	V _{OL}	R _L = ∞			1,2,3		25	mV
Output resistance	R _{O1}	Apply V _{IN} to force V _{OUT} high I _{OUT} = 10 mA	V _S = 18 V	01,02 03	1,2,3		20	Ω
		I _{OUT} = YoʻmA°		04,05 06	1,2,3		8	
				07,08 09	1,2,3		15	
	R _{O2}	Apply V _{IN} to force V _{OUT} low I _{OUT} = 10 mA	V _S = 18 V	01,02 03,07 08,09	1,2,3		15	
				04,05 06	1,2,3		8	

See footnotes at end of table.

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Test	Symbol	Conditions	Device type	Group A subgroups	Limits		Unit
		-55° C \leq T _A \leq +125 $^{\circ}$ C 4.5 V \leq V \leq 18 V unless otherwise specified	туре	subgroups	Min	Max	-
Latch-up protection	I	1/	04,05 06,07 08,09		-500	500	mA
Power supply current	I _{S1}	V _{IN} = 3.0 V (both inputs)	01,02,	1		8.0	mA
			03,07, 08,09,	2,3		12	_
		04,05,	1		1.5	_	
		06	2,3		4.0	_	
	I _{S2}	V _{IN} = 0.0 V, (both inputs)	01,02,	1		0.4	_
			03,07, 08,09	2,3		0.6	_
			04,05,	1		0.15	_
			06	2,3		0.40	
Rise time	t _R	<u>2</u> / <u>3</u> / V _S = 18 V	01,02, 03	9,10,11		60	ns
			04,05,	9		35	-
			06	10,11		60	
			07,08,	9		30	
			09	10,11		40	
Fall time	t _F		01,02, 03,07, 08,09	9,10,11		40	-
			04,05,	9		35	
			06	10,11		60	

See footnotes at end of table.

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	TABLE I.	Electrical performance characte	eristics - Cor	tinued.			
Test	Symbol	Conditions	Device	Group A subgroups	Limi	ts	Unit
		-55° C \leq T _A \leq +125 $^{\circ}$ C 4.5 V \leq V _S \leq 18 V unless otherwise specified	type	subgroups	Min	Max	-
Delay time	t _{D1}	<u>2</u> / <u>3</u> / V _S = 18 V	01,02, 03	9,10,11		60	ns
			04,05,	9		75	_
			06	10,11		100	
			07,08	9		30	_
			09	10,11		40	_
	t _{D2}		01,02, 03	9,10,11		120	_
		04,05,	9		75	_	
			06	10,11		100	_
			07,08, 09	9		50	_
			09	10,11		60	

^{1/} Tested initially and after any design changes which may affect the performance of the device.

3/ For device types 01, 04, and 07, see figure 2. For device types 02, 05, and 08, see figure 3. For device types 03, 06, and 09 inverting drivers, see figure 2. For device types 03, 06, and 09 noninverting drivers, see figure 3.

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DEFENSE ELECTRONICS SUPPLY CENTER
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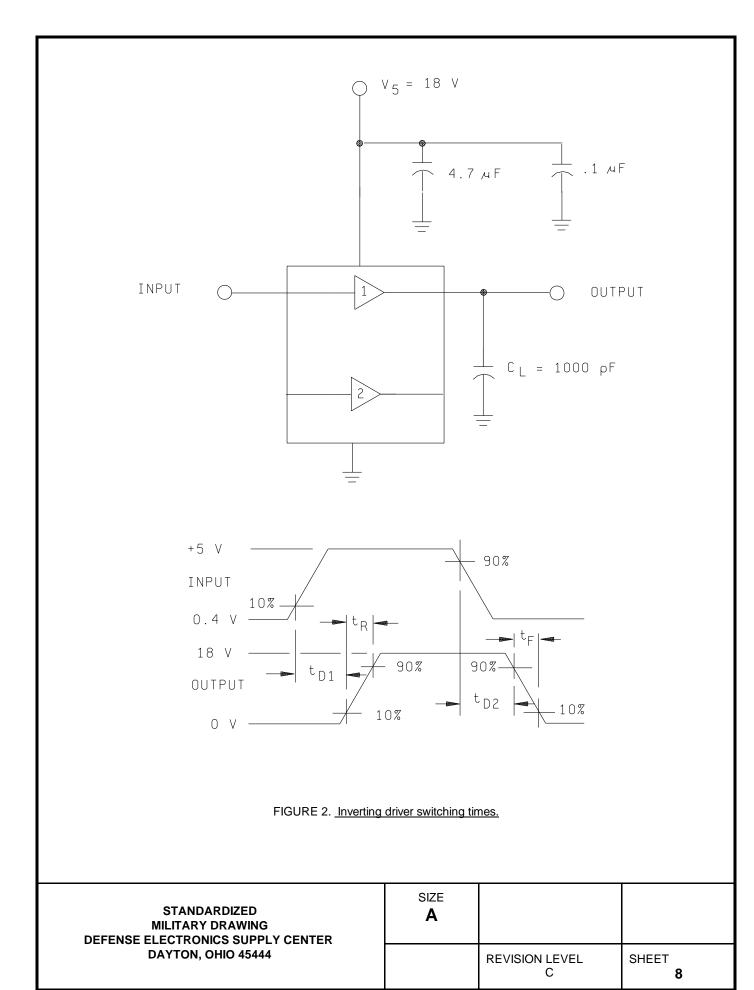
^{2/} Subgroups 10 and 11 are guaranteed if not tested to the limits as specified in table I herein.

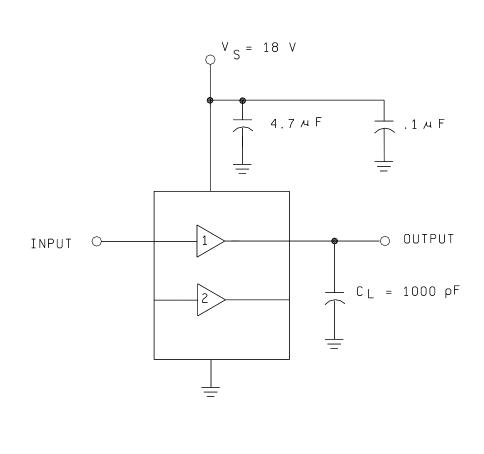
Device types	01, 04, ar	nd 07	02, 05, ar	nd 08	03, 06, ar	nd 09
Case outlines	Р	2	Р	2	Р	2
Terminal number	Terminal	symbol	Terminal	symbol	Terminal	symbol
1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20	NC IN A GND IN B OUT B OUT A NC	NCC A D B C NCC B	NC IN A GND IN B OUT B V OUT A NC	NCC A D B C NCC B NCC B NCC B NCC B NCC C C NCC C NCC C NCC C NCC NC	NC IN A GND IN B OUT B VSUT A NC	NCC A D B C NCC NC B NCC B NCC NCC NCC NCC NCC

NC = No connection

FIGURE 1. <u>Terminal connections</u>.

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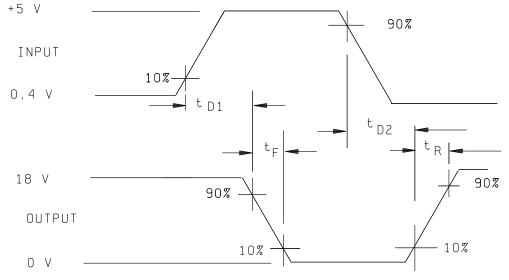


FIGURE 3. Noninverting driver switching time.

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TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups (per method 5005, table I)
Interim electrical parameters (method 5004)	
Final electrical test parameters (method 5004)	1*, 2, 3
Group A test requirements (method 5005)	1, 2, 3, 9, 10**, 11**
Groups C and D end-point electrical parameters (method 5005)	1

- 3.7 <u>Certificate of conformance</u>. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.
- 3.8 Notification of change. Notification of change to DESC-EC shall be required in accordance with MIL-STD-883 (see 3.1 herein).
- 3.9 <u>Verification and review</u>. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore of the reviewer.
 - 4. QUALITY ASSURANCE PROVISIONS
- 4.1 <u>Sampling and inspection</u>. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).
- 4.2 <u>Screening</u>. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
 - a. Burn-in test, method 1015 of MIL-STD-883.
 - (1) Test condition A, B, C, or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015 of MIL-STD-883.
 - (2) $T_A = +125^{\circ} C$, minimum.
 - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim parameter tests prior to burn-in are optional at the discretion of the manufacturer. electrical
- 4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.

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^{*} PDA applies to subgroup 1.
** Subgroups 10 and 11, if not tested, shall be guaranteed to the specified limits in table I.

4.3.1 Group A inspection.

- Tests shall be as specified in table II herein.
- b. Subgroups 4, 5, 6, 7, and 8 in table I, method 5005 of MIL-STD-883 shall be omitted.
- c. O/V (latch-up) tests shall be measured only for initial qualification and after process or design changes which may affect the performance of the device. Latch-up tests shall be considered destructive. Test all applicable pins on three devices with zero failures.

4.3.2 Groups C and D inspections.

- a. End-point electrical parameters shall be as specified in table II herein.
- b. Steady-state life test conditions, method 1005 of MIL-STD-883:
- (1) Test condition A, B, C, or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005 of MIL-STD-883.
 - (2) $T_A = +125^{\circ} C$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

PACKAGING

- 5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.
- 6. NOTES
- 6.1 <u>Intended use.</u> Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.
- 6.2 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-481 using DD Form 1693, Engineering Change Proposal (Short Form).
- 6.4 <u>Record of users</u>. Military and industrial users shall inform Defense Electronics Supply Center when a system application requires configuration control and the applicable SMD. DESC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronics devices (FSC 5962) should contact DESC-EC, telephone (513) 296-6047.
- 6.5 <u>Comments</u>. Comments on this drawing should be directed to DESC-EC, Dayton, Ohio 45444, or telephone 513-296-5377.
- 6.6 <u>Approved sources of supply</u>. Approved sources of supply are listed in MIL-BUL-103. The vendors listed in MIL-BUL-103 vendors listed in MIL-BUL-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DESC-EC.

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STANDARDIZED MILITARY DRAWING SOURCE APPROVAL BULLETIN

DATE: 92-10-22

Approved sources of supply for SMD 5962-88503 are listed below for immediate acquisition only and shall be added to MIL-BUL-103 during the next revision. MIL-BUL-103 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DESC-EC. This bulletin is superseded by the next dated revision of MIL-BUL-103.

Standardized military drawing PIN	Vendor CAGE number	Vendor similar PIN <u>1</u> /
5962-8850301PX	1ES66 60496	TSC426MJA/883 MIC426AJBQ
5962-88503012X	1ES66	TSC426MNP/883
5962-8850302PX	1ES66 60496	TSC427MJA/883 MIC427AJBQ
5962-88503022X	1ES66	TSC427MNP/883
5962-8850303PX	1ES66 60496	TSC428MJA/883 MIC428AJBQ
5962-88503032X	1ES66	TSC428MNP/883
5962-8850304PX	60496	MIC4423AJBQ
5962-88503042X	2/	TSC4423MNP/883
5962-8850305PX	60496	MIC4424AJBQ
5962-88503052X	2/	TSC4424MNP/883
5962-8850306PX	60496	MIC4425AJBQ
5962-88503062X	2/	TSC4425MNP/883
5962-8850307PX	60496	MIC4426AJBQ
5962-88503072X	2/	TSC4426MNP/883
5962-8850308PX	60496	MIC4427AJBQ
5962-88503082X	2/	TSC4427MNP/883
5962-8850309PX	60496	MIC4428AJBQ
5962-88503092X	2/	TSC4428MNP/883

^{1/ &}lt;u>Caution</u>. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

^{2/} No longer available from an approved source of supply.

STANDARDIZED MILITARY DRAWING SOURCE APPROVAL BULLETIN - Continued.

Vendor CAGEVendor namenumberand address

1ES66 Maxim Integrated Products

Maxim Integrated Products 120 San Gabriel Drive Sunnyvale, CA 94086

60496 Micrel, Incorporated

Micrel, Incorporated 560 Oakmead Parkway Sunnyvale, CA 94086

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in this information bulletin